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Details

Product Status	Active
Core Processor	e200z0h
Core Size	32-Bit Single-Core
Speed	64MHz
Connectivity	CANbus, I ² C, LINbus, SCI, SPI
Peripherals	DMA, POR, PWM, WDT
Number of I/O	79
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	64K x 8
RAM Size	48K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 28x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/spc5604ck0mll6

1 Introduction

1.1 Document overview

This document describes the features of the family and options available within the family members, and highlights important electrical and physical characteristics of the device. To ensure a complete understanding of the device functionality, refer also to the device reference manual and errata sheet.

1.2 Description

The MPC5604B/C is a family of next generation microcontrollers built on the Power Architecture® embedded category.

The MPC5604B/C family of 32-bit microcontrollers is the latest achievement in integrated automotive application controllers. It belongs to an expanding family of automotive-focused products designed to address the next wave of body electronics applications within the vehicle. The advanced and cost-efficient host processor core of this automotive controller family complies with the Power Architecture embedded category and only implements the VLE (variable-length encoding) APU, providing improved code density. It operates at speeds of up to 64 MHz and offers high performance processing optimized for low power consumption. It capitalizes on the available development infrastructure of current Power Architecture devices and is supported with software drivers, operating systems and configuration code to assist with users implementations.

2 Block diagram

Figure 1 shows a top-level block diagram of the MPC5604B/C device series.

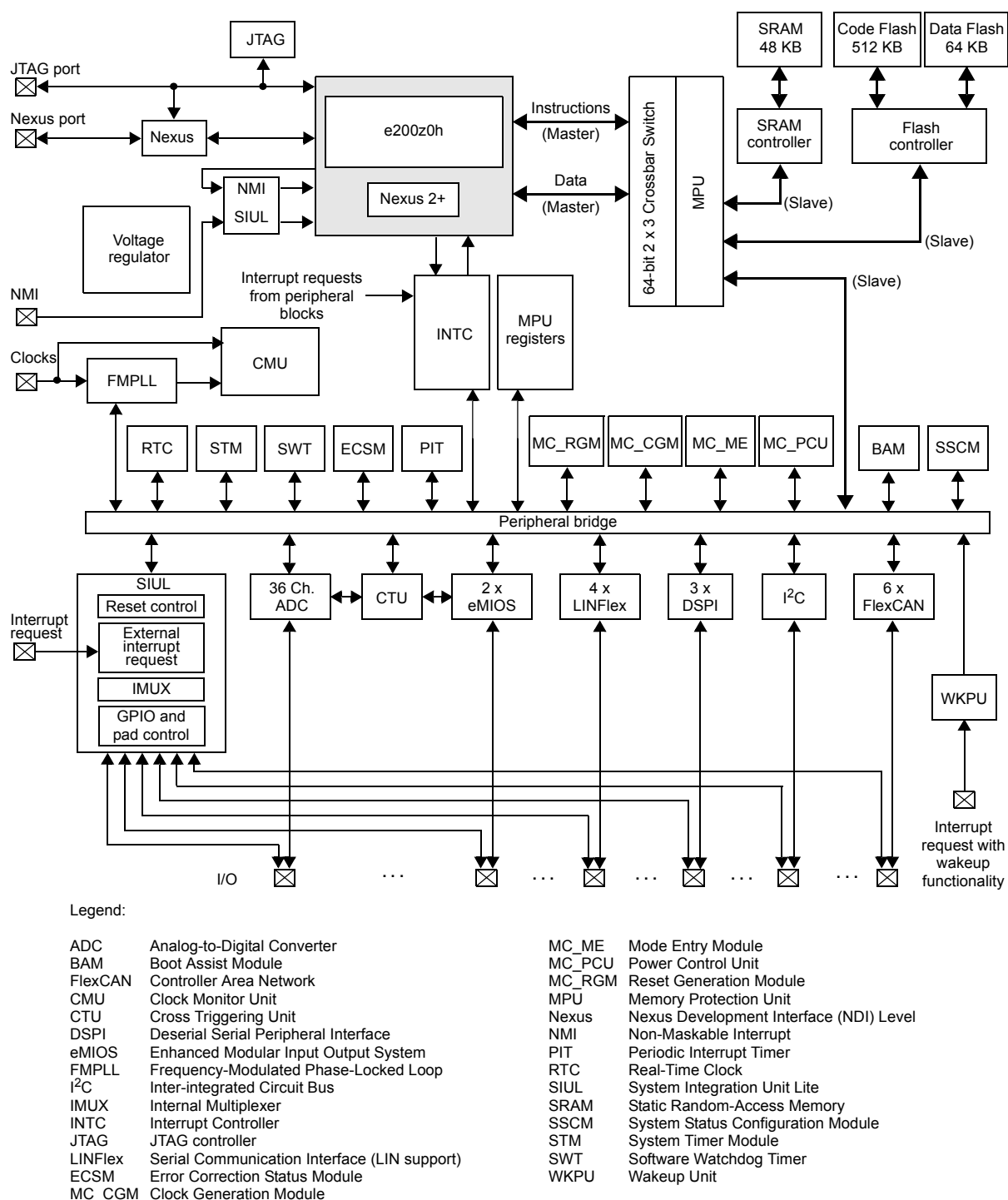
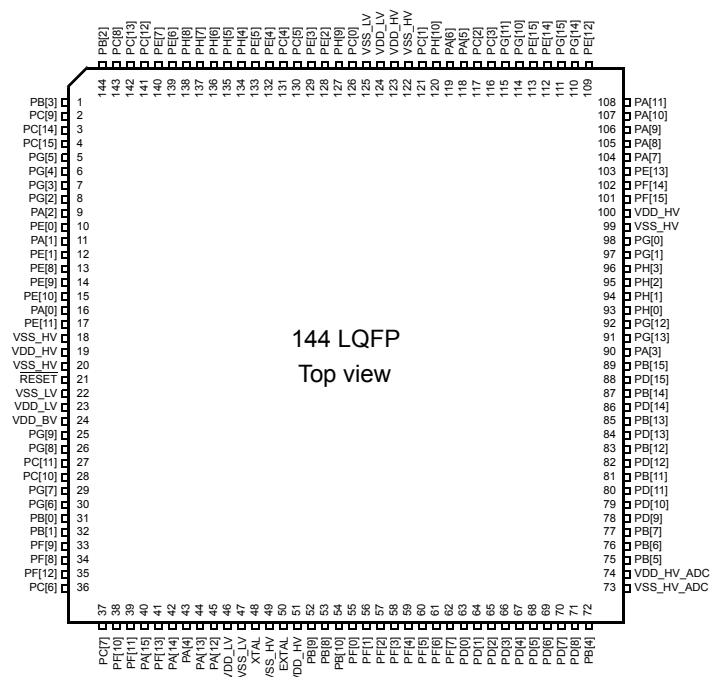


Figure 1. MPC5604B/C block diagram



Note:

Availability of port pin alternate functions depends on product selection.

Figure 5. LQFP 144-pin configuration

	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	
A	PC[8]	PC[13]	NC	NC	PH[8]	PH[4]	PC[5]	PC[0]	NC	NC	PC[2]	NC	PE[15]	NC	NC	NC	A
B	PC[9]	PB[2]	NC	PC[12]	PE[6]	PH[5]	PC[4]	PH[9]	PH[10]	NC	PC[3]	PG[11]	PG[15]	PG[14]	PA[11]	PA[10]	B
C	PC[14]	VDD_HV	PB[3]	PE[7]	PH[7]	PE[5]	PE[3]	VSS_LV	PC[1]	NC	PA[5]	NC	PE[14]	PE[12]	PA[9]	PA[8]	C
D	NC	NC	PC[15]	NC	PH[6]	PE[4]	PE[2]	VDD_LV	VDD_HV	NC	PA[6]	NC	PG[10]	PF[14]	PE[13]	PA[7]	D
E	PG[4]	PG[5]	PG[3]	PG[2]									PG[1]	PG[0]	PF[15]	VDD_HV	E
F	PE[0]	PA[2]	PA[1]	PE[1]									PH[0]	PH[1]	PH[3]	PH[2]	F
G	PE[9]	PE[8]	PE[10]	PA[0]									VDD_HV	NC	NC	MSEO	G
H	VSS_HV	PE[11]	VDD_HV	NC									MDO3	MDO2	MDO0	MDO1	H
J	RESET	VSS_LV	NC	NC									NC	NC	NC	NC	J
K	EVTI	NC	VDD_BV	VDD_LV									NC	PG[12]	PA[3]	PG[13]	K
L	PG[9]	PG[8]	NC	EVTO									PB[15]	PD[15]	PD[14]	PB[14]	L
M	PG[7]	PG[6]	PC[10]	PC[11]									PB[13]	PD[13]	PD[12]	PB[12]	M
N	PB[1]	PF[9]	PB[0]	NC	NC	PA[4]	VSS_LV	EXTAL	VDD_HV	PF[0]	PF[4]	NC	PB[11]	PD[10]	PD[9]	PD[11]	N
P	PF[8]	NC	PC[7]	NC	NC	PA[14]	VDD_LV	XTAL	PB[10]	PF[1]	PF[5]	PD[0]	PD[3]	VDD_HV_ADC	PB[6]	PB[7]	P
R	PF[12]	PC[6]	PF[10]	PF[11]	VDD_HV	PA[15]	PA[13]	NC	OSC32K_XTAL	PF[3]	PF[7]	PD[2]	PD[4]	PD[7]	VSS_HV_ADC	PB[5]	R
T	NC	NC	NC	MCKO	NC	PF[13]	PA[12]	NC	OSC32K_EXTAL	PF[2]	PF[6]	PD[1]	PD[5]	PD[6]	PD[8]	PB[4]	T
	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	

Note: 208 MAPBGA available only as development package for Nexus 2+.

NC = Not connected

Figure 6. 208 MAPBGA configuration

3.2 Pad configuration during reset phases

All pads have a fixed configuration under reset.

During the power-up phase, all pads are forced to tristate.

After power-up phase, all pads are forced to tristate with the following exceptions:

- PA[9] (FAB) is pull-down. Without external strong pull-up the device starts fetching from flash.
- PA[8] (ABS[0]) is pull-up.
- RESET pad is driven low. This is pull-up only after PHASE2 reset completion.
- JTAG pads (TCK, TMS and TDI) are pull-up whilst TDO remains tristate.
- Precise ADC pads (PB[7:4] and PD[11:0]) are left tristate (no output buffer available).
- Main oscillator pads (EXTAL, XTAL) are tristate.
- Nexus output pads (MDO[n], MCKO, EVTO, MSEO) are forced to output.

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function ¹	Function	Peripheral	I/O direction ²	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA ³
PC[9]	PCR[41]	AF0 AF1 AF2 AF3 — —	GPIO[41] — — — LIN2RX WKPU[13] ⁴	SIUL — — — LINFlex_2 WKPU	I/O — — — I I	S	Tristate	2	2	2	2	B1
PC[10]	PCR[42]	AF0 AF1 AF2 AF3	GPIO[42] CAN1TX CAN4TX ¹¹ MA[1]	SIUL FlexCAN_1 FlexCAN_4 ADC	I/O O O O	M	Tristate	13	13	22	28	M3
PC[11]	PCR[43]	AF0 AF1 AF2 AF3 — — —	GPIO[43] — — — CAN1RX CAN4RX ¹¹ WKPU[5] ⁴	SIUL — — — FlexCAN_1 FlexCAN_4 WKPU	I/O — — — I I I	S	Tristate	—	—	21	27	M4
PC[12]	PCR[44]	AF0 AF1 AF2 AF3 —	GPIO[44] E0UC[12] — — SIN_2	SIUL eMIOS_0 — — DSPI_2	I/O I/O — — I	M	Tristate	—	—	97	141	B4
PC[13]	PCR[45]	AF0 AF1 AF2 AF3	GPIO[45] E0UC[13] SOUT_2 —	SIUL eMIOS_0 DSPI_2 —	I/O I/O O —	S	Tristate	—	—	98	142	A2
PC[14]	PCR[46]	AF0 AF1 AF2 AF3 —	GPIO[46] E0UC[14] SCK_2 — EIRQ[8]	SIUL eMIOS_0 DSPI_2 — SIUL	I/O I/O I/O — I	S	Tristate	—	—	3	3	C1
PC[15]	PCR[47]	AF0 AF1 AF2 AF3	GPIO[47] E0UC[15] CS0_2 —	SIUL eMIOS_0 DSPI_2 —	I/O I/O I/O —	M	Tristate	—	—	4	4	D3
PD[0]	PCR[48]	AF0 AF1 AF2 AF3 —	GPIO[48] — — — GPI[4]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	41	63	P12

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function ¹	Function	Peripheral	I/O direction ²	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA ³
PE[1]	PCR[65]	AF0 AF1 AF2 AF3	GPIO[65] E0UC[17] CAN5TX ¹¹ —	SIUL eMIOS_0 FlexCAN_5 —	I/O I/O O —	M	Tristate	—	—	8	12	F4
PE[2]	PCR[66]	AF0 AF1 AF2 AF3 —	GPIO[66] E0UC[18] — — SIN_1	SIUL eMIOS_0 — — DSPI_1	I/O I/O — — I	M	Tristate	—	—	89	128	D7
PE[3]	PCR[67]	AF0 AF1 AF2 AF3	GPIO[67] E0UC[19] SOUT_1 —	SIUL eMIOS_0 DSPI_1 —	I/O I/O O —	M	Tristate	—	—	90	129	C7
PE[4]	PCR[68]	AF0 AF1 AF2 AF3 —	GPIO[68] E0UC[20] SCK_1 — EIRQ[9]	SIUL eMIOS_0 DSPI_1 — SIUL	I/O I/O I/O — I	M	Tristate	—	—	93	132	D6
PE[5]	PCR[69]	AF0 AF1 AF2 AF3	GPIO[69] E0UC[21] CS0_1 MA[2]	SIUL eMIOS_0 DSPI_1 ADC	I/O I/O I/O O	M	Tristate	—	—	94	133	C6
PE[6]	PCR[70]	AF0 AF1 AF2 AF3	GPIO[70] E0UC[22] CS3_0 MA[1]	SIUL eMIOS_0 DSPI_0 ADC	I/O I/O O O	M	Tristate	—	—	95	139	B5
PE[7]	PCR[71]	AF0 AF1 AF2 AF3	GPIO[71] E0UC[23] CS2_0 MA[0]	SIUL eMIOS_0 DSPI_0 ADC	I/O I/O O O	M	Tristate	—	—	96	140	C4
PE[8]	PCR[72]	AF0 AF1 AF2 AF3	GPIO[72] CAN2TX ¹² E0UC[22] CAN3TX ¹¹	SIUL FlexCAN_2 eMIOS_0 FlexCAN_3	I/O O I/O O	M	Tristate	—	—	9	13	G2
PE[9]	PCR[73]	AF0 AF1 AF2 AF3 — — —	GPIO[73] — E0UC[23] — WKPU[7] ⁴ CAN2RX ¹² CAN3RX ¹¹	SIUL — eMIOS_0 — WKPU FlexCAN_2 FlexCAN_3	I/O — I/O — I I I	S	Tristate	—	—	10	14	G1

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function ¹	Function	Peripheral	I/O direction ²	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA ³
PF[2]	PCR[82]	AF0 AF1 AF2 AF3 —	GPIO[82] E0UC[12] CS0_2 — ANS[10]	SIUL eMIOS_0 DSPI_2 — ADC	I/O I/O I/O — I	J	Tristate	—	—	—	57	T10
PF[3]	PCR[83]	AF0 AF1 AF2 AF3 —	GPIO[83] E0UC[13] CS1_2 — ANS[11]	SIUL eMIOS_0 DSPI_2 — ADC	I/O I/O O — I	J	Tristate	—	—	—	58	R10
PF[4]	PCR[84]	AF0 AF1 AF2 AF3 —	GPIO[84] E0UC[14] CS2_2 — ANS[12]	SIUL eMIOS_0 DSPI_2 — ADC	I/O I/O O — I	J	Tristate	—	—	—	59	N11
PF[5]	PCR[85]	AF0 AF1 AF2 AF3 —	GPIO[85] E0UC[22] CS3_2 — ANS[13]	SIUL eMIOS_0 DSPI_2 — ADC	I/O I/O O — I	J	Tristate	—	—	—	60	P11
PF[6]	PCR[86]	AF0 AF1 AF2 AF3 —	GPIO[86] E0UC[23] — — ANS[14]	SIUL eMIOS_0 — — ADC	I/O I/O — — I	J	Tristate	—	—	—	61	T11
PF[7]	PCR[87]	AF0 AF1 AF2 AF3 —	GPIO[87] — — — ANS[15]	SIUL — — — ADC	I/O — — — I	J	Tristate	—	—	—	62	R11
PF[8]	PCR[88]	AF0 AF1 AF2 AF3	GPIO[88] CAN3TX ¹⁴ CS4_0 CAN2TX ¹⁵	SIUL FlexCAN_3 DSPI_0 FlexCAN_2	I/O O O O	M	Tristate	—	—	—	34	P1
PF[9]	PCR[89]	AF0 AF1 AF2 AF3 — —	GPIO[89] — CS5_0 — CAN2RX ¹⁵ CAN3RX ¹⁴	SIUL — DSPI_0 — FlexCAN_2 FlexCAN_3	I/O — O — I I	S	Tristate	—	—	—	33	N2

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function ¹	Function	Peripheral	I/O direction ²	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA ³
PG[11]	PCR[107]	AF0 AF1 AF2 AF3	GPIO[107] E0UC[25] — —	SIUL eMIOS_0 — —	I/O I/O — —	M	Tristate	—	—	—	115	B12
PG[12]	PCR[108]	AF0 AF1 AF2 AF3	GPIO[108] E0UC[26] — —	SIUL eMIOS_0 — —	I/O I/O — —	M	Tristate	—	—	—	92	K14
PG[13]	PCR[109]	AF0 AF1 AF2 AF3	GPIO[109] E0UC[27] — —	SIUL eMIOS_0 — —	I/O I/O — —	M	Tristate	—	—	—	91	K16
PG[14]	PCR[110]	AF0 AF1 AF2 AF3	GPIO[110] E1UC[0] — —	SIUL eMIOS_1 — —	I/O I/O — —	S	Tristate	—	—	—	110	B14
PG[15]	PCR[111]	AF0 AF1 AF2 AF3	GPIO[111] E1UC[1] — —	SIUL eMIOS_1 — —	I/O I/O — —	M	Tristate	—	—	—	111	B13
PH[0]	PCR[112]	AF0 AF1 AF2 AF3 —	GPIO[112] E1UC[2] — — SIN1	SIUL eMIOS_1 — — DSPI_1	I/O I/O — — I	M	Tristate	—	—	—	93	F13
PH[1]	PCR[113]	AF0 AF1 AF2 AF3	GPIO[113] E1UC[3] SOUT1 —	SIUL eMIOS_1 DSPI_1 —	I/O I/O O —	M	Tristate	—	—	—	94	F14
PH[2]	PCR[114]	AF0 AF1 AF2 AF3	GPIO[114] E1UC[4] SCK_1 —	SIUL eMIOS_1 DSPI_1 —	I/O I/O I/O —	M	Tristate	—	—	—	95	F16
PH[3]	PCR[115]	AF0 AF1 AF2 AF3	GPIO[115] E1UC[5] CS0_1 —	SIUL eMIOS_1 DSPI_1 —	I/O I/O I/O —	M	Tristate	—	—	—	96	F15

² C_L includes device and package capacitances ($C_{PKG} < 5$ pF).

3.15.5 I/O pad current specification

The I/O pads are distributed across the I/O supply segment. Each I/O supply segment is associated to a V_{DD}/V_{SS} supply pair as described in Table 22.

Table 22. I/O supply segment

Package	Supply segment					
	1	2	3	4	5	6
208 MAPBGA ¹	Equivalent to 144 LQFP segment pad distribution				MCKO	MDO _n /MSEO
144 LQFP	pin20–pin49	pin51–pin99	pin100–pin122	pin 123–pin19	—	—
100 LQFP	pin16–pin35	pin37–pin69	pin70–pin83	pin 84–pin15	—	—
64 LQFP	pin8–pin26	pin28–pin55	pin56–pin7	—	—	—

¹ 208 MAPBGA available only as development package for Nexus2+

Table 23 provides I/O consumption figures.

In order to ensure device reliability, the average current of the I/O on a single segment should remain below the I_{AVGSEG} maximum value.

Table 23. I/O consumption

Symbol	C		Parameter	Conditions ¹		Value			Unit
						Min	Typ	Max	
I _{SWTSLW} ²	CC	D	Dynamic I/O current for SLOW configuration	C _L = 25 pF	V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	20	mA
					V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	16	
I _{SWTMED} ²	CC	D	Dynamic I/O current for MEDIUM configuration	C _L = 25 pF	V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	29	mA
					V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	17	
I _{SWTFST} ²	CC	D	Dynamic I/O current for FAST configuration	C _L = 25 pF	V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	110	mA
					V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	50	
I _{RMSSLW}	CC	D	Root mean square I/O current for SLOW configuration	C _L = 25 pF, 2 MHz	V _{DD} = 5.0 V ± 10%, PAD3V5V = 0	—	—	2.3	mA
				C _L = 25 pF, 4 MHz		—	—	3.2	
				C _L = 100 pF, 2 MHz		—	—	6.6	
				C _L = 25 pF, 2 MHz	V _{DD} = 3.3 V ± 10%, PAD3V5V = 1	—	—	1.6	
				C _L = 25 pF, 4 MHz		—	—	2.3	
				C _L = 100 pF, 2 MHz		—	—	4.7	

Table 24. I/O weight¹ (continued)

Supply segment			Pad	144/100 LQFP				64 LQFP			
				Weight 5 V		Weight 3.3 V		Weight 5 V		Weight 3.3 V	
144 LQFP	100 LQFP	64 LQFP ²		SRC ³ = 0	SRC = 1	SRC = 0	SRC = 1	SRC = 0	SRC = 1	SRC = 0	SRC = 1
3	3	2	PA[5]	5%	7%	6%	6%	6%	8%	7%	7%
			PA[6]	5%	—	6%	—	5%	—	6%	—
			PH[10]	4%	6%	5%	5%	5%	7%	6%	6%
			PC[1]	5%	—	5%	—	5%	—	5%	—
4	4	3	PC[0]	6%	9%	7%	8%	6%	9%	7%	8%
			PH[9]	7	7	8	8	7	7	8	8
		—	PE[2]	7%	10%	9%	9%	—	—	—	—
		—	PE[3]	8%	11%	9%	9%	—	—	—	—
		3	PC[5]	8%	11%	9%	10%	8%	11%	9%	10%
			PC[4]	8%	12%	10%	10%	8%	12%	10%	10%
		—	PE[4]	8%	12%	10%	11%	—	—	—	—
		—	PE[5]	9%	12%	10%	11%	—	—	—	—
	—	—	PH[4]	9%	13%	11%	11%	—	—	—	—
	—	—	PH[5]	9%	—	11%	—	—	—	—	—
	—	—	PH[6]	9%	13%	11%	12%	—	—	—	—
	—	—	PH[7]	9%	13%	11%	12%	—	—	—	—
	—	—	PH[8]	10%	14%	11%	12%	—	—	—	—
	4	—	PE[6]	10%	14%	12%	12%	—	—	—	—
		—	PE[7]	10%	14%	12%	12%	—	—	—	—
		—	PC[12]	10%	14%	12%	13%	—	—	—	—
		—	PC[13]	10%	—	12%	—	—	—	—	—
		3	PC[8]	10%	—	12%	—	10%	—	12%	—
			PB[2]	10%	15%	12%	13%	10%	15%	12%	13%

¹ V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = –40 to 125 °C, unless otherwise specified

² Segments shown apply to MPC560xB devices only

³ SRC: “Slew Rate Control” bit in SIU_PCR

3.16 RESET electrical characteristics

The device implements a dedicated bidirectional RESET pin.

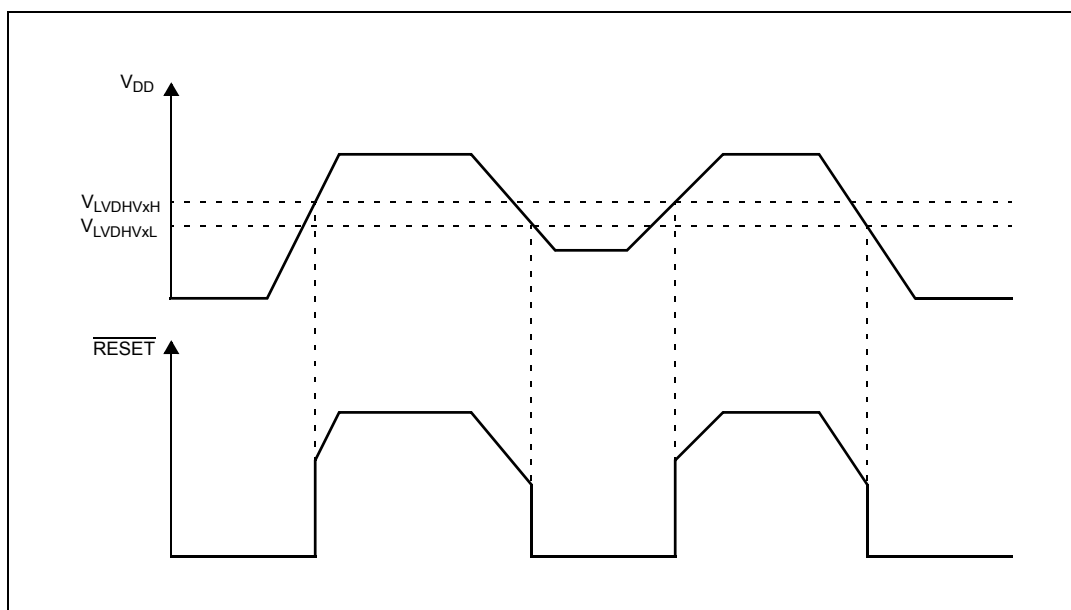


Figure 13. Low voltage detector vs reset

Table 27. Low voltage detector electrical characteristics

Symbol		C	Parameter	Conditions ¹	Value			Unit
					Min	Typ	Max	
V _{PORUP}	SR	P	Supply for functional POR module	—	1.0	—	5.5	V
V _{PORH}	CC	P	Power-on reset threshold	T _A = 25 °C, after trimming	1.5	—	2.6	
		T		—	1.5	—	2.6	
V _{LVDHV3H}	CC	T	LVDHV3 low voltage detector high threshold	—	—	—	2.95	
V _{LVDHV3L}	CC	P	LVDHV3 low voltage detector low threshold		2.6	—	2.9	
V _{LVDHV5H}	CC	T	LVDHV5 low voltage detector high threshold		—	—	4.5	
V _{LVDHV5L}	CC	P	LVDHV5 low voltage detector low threshold		3.8	—	4.4	
V _{LVDLVCORL}	CC	P	LVDLVCOR low voltage detector low threshold		1.08	—	1.16	
V _{LVDLVBKPL}	CC	P	LVDLVBKP low voltage detector low threshold		1.08	—	1.16	

¹ V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = -40 to 125 °C, unless otherwise specified

3.18 Power consumption

Table 28 provides DC electrical characteristics for significant application modes. These values are indicative values; actual consumption depends on the application.

Table 35. ESD absolute maximum ratings^{1 2}

Symbol	C		Ratings	Conditions	Class	Max value	Unit
V _{ESD(HBM)}	CC	T	Electrostatic discharge voltage (Human Body Model)	T _A = 25 °C conforming to AEC-Q100-002	H1C	2000	V
V _{ESD(MM)}	CC	T	Electrostatic discharge voltage (Machine Model)	T _A = 25 °C conforming to AEC-Q100-003	M2	200	
V _{ESD(CDM)}	CC	T	Electrostatic discharge voltage (Charged Device Model)	T _A = 25 °C conforming to AEC-Q100-011	C3A	500 750 (corners)	

¹ All ESD testing is in conformity with CDF-AEC-Q100 Stress Test Qualification for Automotive Grade Integrated Circuits.

² A device will be defined as a failure if after exposure to ESD pulses the device no longer meets the device specification requirements. Complete DC parametric and functional testing shall be performed per applicable device specification at room temperature followed by hot temperature, unless specified otherwise in the device specification.

3.20.3.2 Static latch-up (LU)

Two complementary static tests are required on six parts to assess the latch-up performance:

- A supply overvoltage is applied to each power supply pin.
- A current injection is applied to each input, output and configurable I/O pin.

These tests are compliant with the EIA/JESD 78 IC latch-up standard.

Table 36. Latch-up results

Symbol	C		Parameter	Conditions	Class
LU	CC	T	Static latch-up class	T _A = 125 °C conforming to JESD 78	II level A

3.21 Fast external crystal oscillator (4 to 16 MHz) electrical characteristics

The device provides an oscillator/resonator driver. [Figure 14](#) describes a simple model of the internal oscillator driver and provides an example of a connection for an oscillator or a resonator.

[Table 37](#) provides the parameter description of 4 MHz to 16 MHz crystals used for the design simulations.

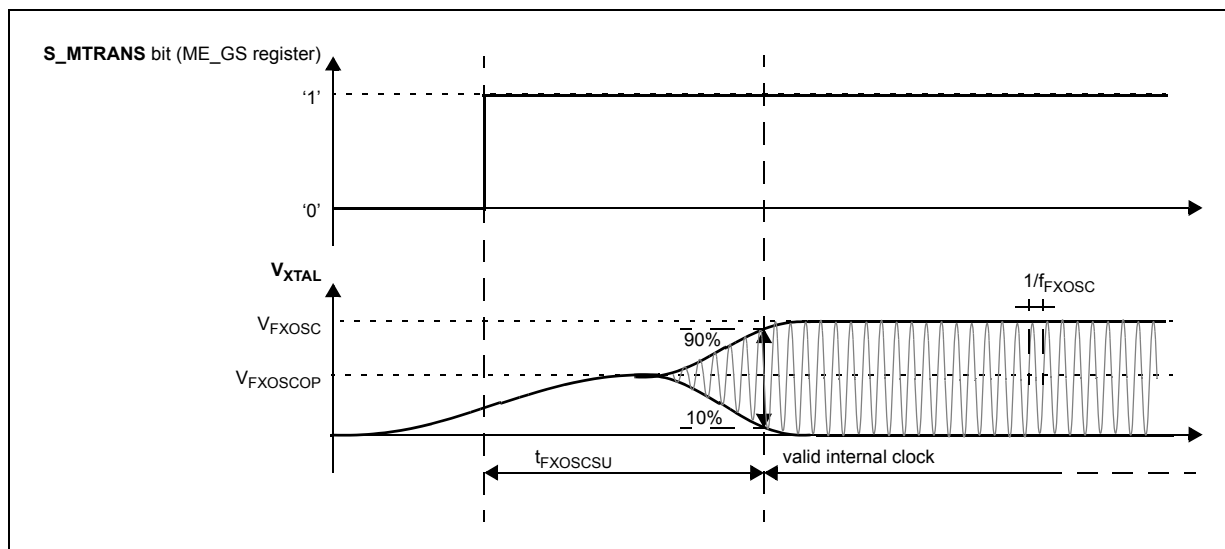


Figure 15. Fast external crystal oscillator (4 to 16 MHz) timing diagram

Table 42. Fast internal RC oscillator (16 MHz) electrical characteristics (continued)

Symbol		C	Parameter	Conditions ¹		Value			Unit
						Min	Typ	Max	
I _{FIRCSTOP}	CC	T	Fast internal RC oscillator high frequency and system clock current in stop mode	T _A = 25 °C	sysclk = off	—	500	—	μA
					sysclk = 2 MHz	—	600	—	
					sysclk = 4 MHz	—	700	—	
					sysclk = 8 MHz	—	900	—	
					sysclk = 16 MHz	—	1250	—	
t _{FIRCSU}	CC	C	Fast internal RC oscillator start-up time	V _{DD} = 5.0 V ± 10%		—	1.1	2.0	μs
Δ _{FIRCPRE}	CC	T	Fast internal RC oscillator precision after software trimming of f _{FIRC}	T _A = 25 °C		–1	—	+1	%
Δ _{FIRCTRM}	CC	T	Fast internal RC oscillator trimming step	T _A = 25 °C		—	1.6		%
Δ _{FIRCVAR}	CC	P	Fast internal RC oscillator variation in overtemperature and supply with respect to f _{FIRC} at T _A = 25 °C in high-frequency configuration	—		–5	—	+5	%

¹ V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = –40 to 125 °C, unless otherwise specified.

² This does not include consumption linked to clock tree toggling and peripherals consumption when RC oscillator is ON.

3.25 Slow internal RC oscillator (128 kHz) electrical characteristics

The device provides a 128 kHz slow internal RC oscillator. This can be used as the reference clock for the RTC module.

Table 43. Slow internal RC oscillator (128 kHz) electrical characteristics

Symbol	C	Parameter	Conditions ¹	Value			Unit
				Min	Typ	Max	
f _{SIRC}	CC	P	T _A = 25 °C, trimmed	—	128	—	kHz
	SR		—	100	—	150	
I _{SIRC} ²	CC	C	Slow internal RC oscillator low frequency current T _A = 25 °C, trimmed	—	—	5	μA
t _{SIRCSU}	CC	P	Slow internal RC oscillator start-up time T _A = 25 °C, V _{DD} = 5.0 V ± 10%	—	8	12	μs
Δ _{SIRCPRE}	CC	C	Slow internal RC oscillator precision after software trimming of f _{SIRC} T _A = 25 °C	–2	—	+2	%
Δ _{SIRCTRM}	CC	C	Slow internal RC oscillator trimming step	—	2.7	—	
Δ _{SIRCVAR}	CC	C	Slow internal RC oscillator variation in temperature and supply with respect to f _{SIRC} at T _A = 55 °C in high frequency configuration	–10	—	+10	%

Package pinouts and signal descriptions

possible, ideally infinite. This capacitor contributes to attenuating the noise present on the input pin; furthermore, it sources charge during the sampling phase, when the analog signal source is a high-impedance source.

A real filter can typically be obtained by using a series resistance with a capacitor on the input pin (simple RC filter). The RC filtering may be limited according to the value of source impedance of the transducer or circuit supplying the analog signal to be measured. The filter at the input pins must be designed taking into account the dynamic characteristics of the input signal (bandwidth) and the equivalent input impedance of the ADC itself.

In fact a current sink contributor is represented by the charge sharing effects with the sampling capacitance: being C_S and C_{P2} substantially two switched capacitances, with a frequency equal to the conversion rate of the ADC, it can be seen as a resistive path to ground. For instance, assuming a conversion rate of 1 MHz, with $C_S + C_{P2}$ equal to 3 pF, a resistance of 330 kΩ is obtained ($R_{EQ} = 1 / (f_c \times (C_S + C_{P2}))$), where f_c represents the conversion rate at the considered channel). To minimize the error induced by the voltage partitioning between this resistance (sampled voltage on $C_S + C_{P2}$) and the sum of $R_S + R_F$, the external circuit must be designed to respect the Equation 4:

Eqn. 4

$$V_A \cdot \frac{R_S + R_F}{R_{EQ}} < \frac{1}{2} \text{ LSB}$$

Equation 4 generates a constraint for external network design, in particular on a resistive path.

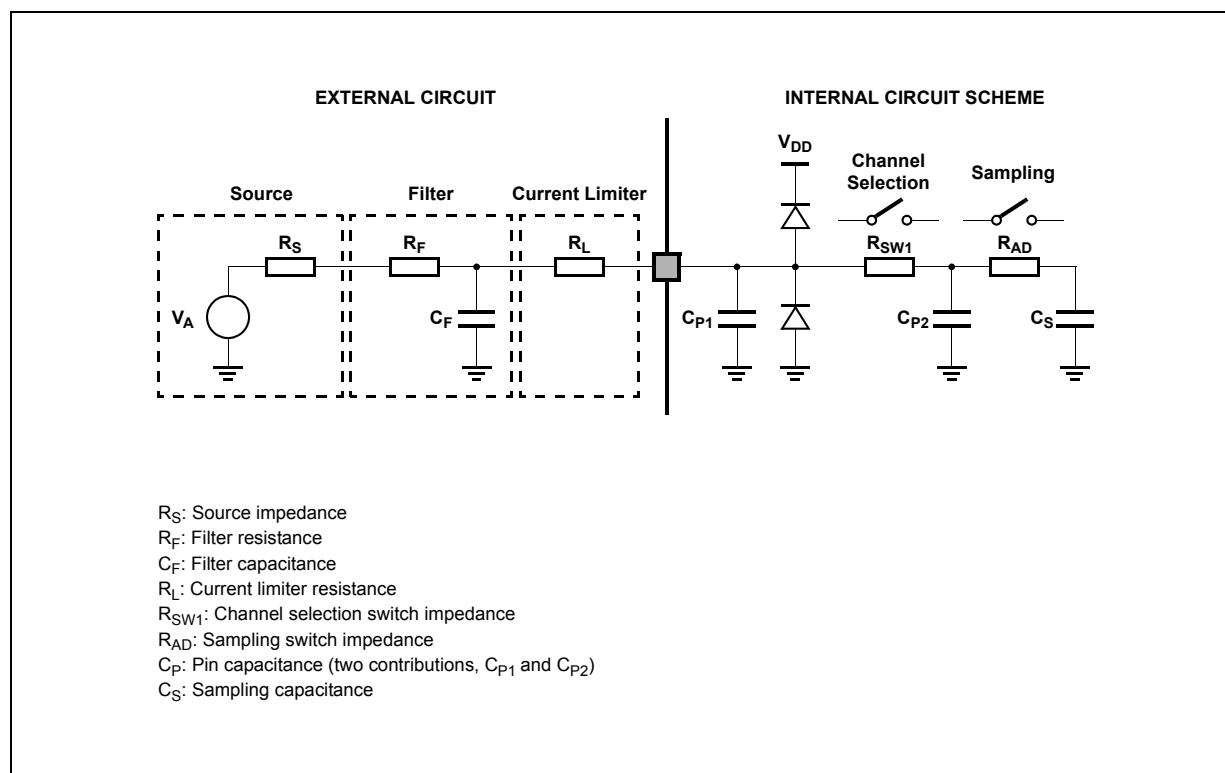


Figure 20. Input equivalent circuit (precise channels)

4.1.3 144 LQFP

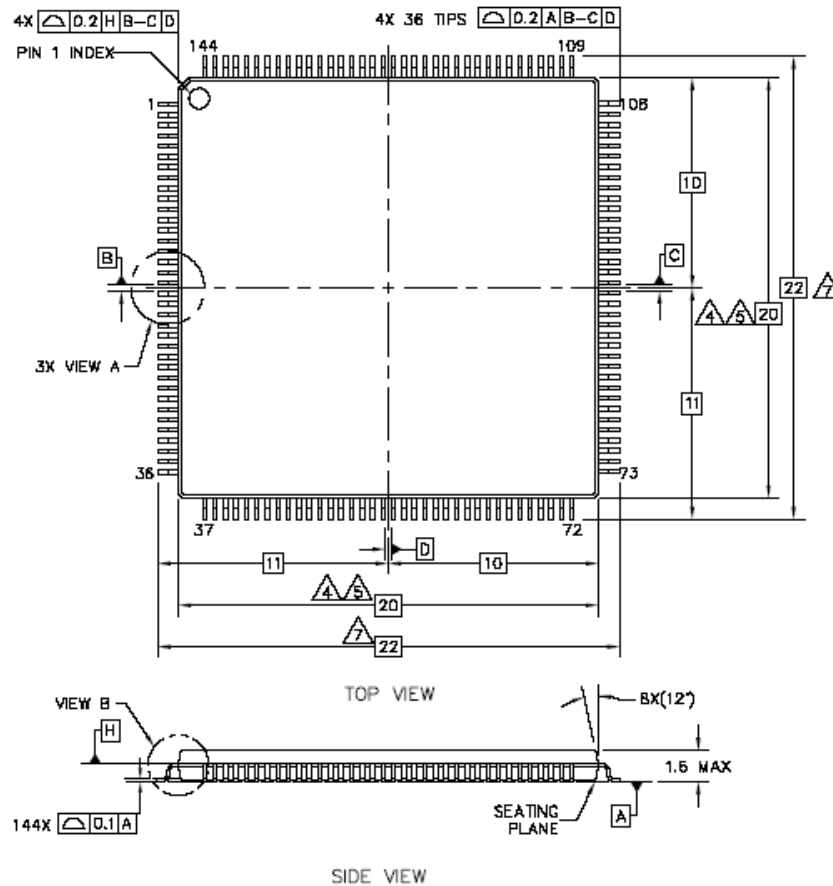
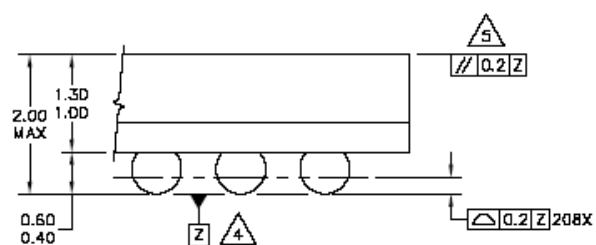


Figure 41. 144 LQFP package mechanical drawing (1 of 2)



DETAIL K
(ROTATED 90° CLOCKWISE)

NOTES:

1. ALL DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
3. DIMENSION **b** IS MEASURED AT THE MAXIMUM SOLDER BALL DIAMETER, PARALLEL TO DATUM PLANE Z.
4. DATUM Z (SEATING PLANE) IS DEFINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS.
5. PARALLELISM MEASUREMENT SHALL EXCLUDE ANY EFFECT OF MARK ON TOP SURFACE OF PACKAGE.
6. PACKAGE CODE SUMMARY:
MAP BGA: 5253
MAP BGA PGE DIE: 5371

 FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED.	MECHANICAL OUTLINE	PRINT VERSION NOT TO SCALE
TITLE: 20B I/O MAP BGA, 17 X 17 PKG. 1-MM PITCH	DOCUMENT NO: 98ARS238B2W	REV: E
	CASE NUMBER: 1159A-01	28 MAR 2007
	STANDARD: JEDEC MO-151 AAF-1	

Figure 44. 208 MAPBGA package mechanical drawing (2 of 2)

Table 50. Revision history (continued)

Revision	Date	Description of Changes
4	06-Aug-2009	Updated Figure 6 Table 12 • V_{DD_ADC}: changed min value for “relative to V_{DD}” condition • V_{IN}: changed min value for “relative to V_{DD}” condition • I_{CORELV}: added new row Table 14 • $T_{A\ C-Grade\ Part}$, $T_{J\ C-Grade\ Part}$, $T_{A\ V-Grade\ Part}$, $T_{J\ V-Grade\ Part}$, $T_{A\ M-Grade\ Part}$, $T_{J\ M-Grade\ Part}$: added new rows • Changed capacitance value in footnote Table 21 • MEDIUM configuration: added condition for $PAD3V5V = 0$ Updated Figure 10 Table 26 • C_{DEC1}: changed min value • I_{MREG}: changed max value • I_{DD_BV}: added max value footnote Table 27 • $V_{LVDHV3H}$: changed max value • $V_{LVDHV3L}$: added max value • $V_{LVDHV5H}$: changed max value • $V_{LVDHV5L}$: added max value Updated Table 28 Table 30 • Retention: deleted min value footnote for “Blocks with 100,000 P/E cycles” Table 38 • I_{FXOSC}: added typ value Table 40 • V_{SXOSC}: changed typ value • $T_{SXOSCSU}$: added max value footnote Table 41 • Δt_{LTJIT}: added max value Updated Figure 38

Table 50. Revision history (continued)

Revision	Date	Description of Changes
6	15-Mar-2010	In the "Introduction" section, relocated a note. In the "MPC5604B/C device comparison" table, added footnote regarding SCI and CAN. In the "Absolute maximum ratings" table, removed the min value of V_{IN} relative to V_{DD}. In the "Recommended operating conditions (3.3 V)" table: • T_A C-Grade Part, T_J C-Grade Part, T_A V-Grade Part, T_J V-Grade Part, T_A M-Grade Part, T_J M-Grade Part: added new rows. • T_{VDD}: made single row. In the "LQFP thermal characteristics" table, added more rows. Removed "208 MAPBGA thermal characteristics" table. In the "I/O consumption" table: • Removed I_{DYNSEG} row. • Added "I/O weight" table. In the "Voltage regulator electrical characteristics" table: • Updated the values. • Removed $I_{VREGREF}$ and $I_{VREDLVD12}$. • Added a note about I_{DD_BC}. In the "Low voltage monitor electrical characteristics" table: • Updated V_{PORH} values. • Updated $V_{LVDLVCORL}$ value. Entirely updated the "Low voltage power domain electrical characteristics" table. In the "Program and erase specifications" table, inserted T_{eslat} row. Entirely updated the "Flash power supply DC electrical characteristics" table. Entirely updated the "Start-up time/Switch-off time" table. In the "Crystal oscillator and resonator connection scheme" figure, relocated a note. In the "Slow external crystal oscillator (32 kHz) electrical characteristics" table: • Removed g_{mSXOSC} row. • Inserted values of $I_{SXOSCBIAS}$. Entirely updated the "Fast internal RC oscillator (16 MHz) electrical characteristics" table. In the "ADC conversion characteristics" table: updated the description of the conditions of t_{ADC_PU} and t_{ADC_S}. Entirely updated the "DSPI characteristics" table. In the "Orderable part number summary" table, modified some orderable part number. Updated the "Commercial product code structure" figure. Removed the note about the condition from "Flash read access timing" table Removed the notes that assert the values need to be confirmed before validation Exchanged the order of "LQFP 100-pin configuration" and "LQFP 144-pin configuration" Exchanged the order of "LQFP 100-pin package mechanical drawing" and "LQFP 144-pin package mechanical drawing"

Table 50. Revision history (continued)

Revision	Date	Description of Changes
9	16 June 2011	Formatting and minor editorial changes throughout Harmonized oscillator nomenclature Removed all instances of note “All 64 LQFP information is indicative and must be confirmed during silicon validation.” Device comparison table: changed temperature value in footnote 2 from 105 °C to 125 °C MPC560xB LQFP 64-pin configuration and MPC560xC LQFP 64-pin configuration: renamed pin 6 from VPP_TEST to VSS_HV Removed “Pin Muxing” section; added sections “Pad configuration during reset phases”, “Voltage supply pins”, “Pad types”, “System pins”, “Functional ports”, and “Nexus 2+ pins” Section “NVUSRO register”: edited content to separate configuration into electrical parameters and digital functionality; updated footnote describing default value of ‘1’ in field descriptions NVUSRO[PAD3V5V] and NVUSRO[OSCILLATOR_MARGIN] Added section “NVUSRO[WATCHDOG_EN] field description” Recommended operating conditions (3.3 V) and Recommended operating conditions (5.0 V): updated conditions for ambient and junction temperature characteristics I/O input DC electrical characteristics: updated I_{LKG} characteristics Section “I/O pad current specification”: removed content referencing the I_{DYNSEG} maximum value I/O consumption: replaced instances of “Root medium square” with “Root mean square” I/O weight: replaced instances of bit “SRE” with “SRC”; added pads PH[9] and PH[10]; added supply segments; removed weight values in 64-pin LQFP for pads that do not exist in that package Reset electrical characteristics: updated parameter classification for I_{WPU} Updated Voltage regulator electrical characteristics Section “Low voltage detector electrical characteristics”: changed title (was “Voltage monitor electrical characteristics”); added event status flag names found in RGM chapter of device reference manual to POR module and LVD descriptions; replaced instances of “Low voltage monitor” with “Low voltage detector”; updated values for $V_{LVDLVBKPL}$ and $V_{LVDLVCORL}$; replaced “LVD_DIGBKP” with “LVDLVBKP” in note Updated section “Power consumption” Fast external crystal oscillator (4 to 16 MHz) electrical characteristics: updated parameter classification for $V_{FXOSCOP}$ Crystal oscillator and resonator connection scheme: added footnote about possibility of adding a series resistor Slow external crystal oscillator (32 kHz) electrical characteristics: updated footnote 1 FMPLL electrical characteristics: added short term jitter characteristics; inserted “—” in empty min value cell of t_{lock} row Section “Input impedance and ADC accuracy”: changed “V_A/V_{A2}” to “V_{A2}/V_A” in Equation 11 ADC input leakage current: updated I_{LKG} characteristics ADC conversion characteristics: updated symbols On-chip peripherals current consumption: changed “supply current on “$V_{DD_HV_ADC}$” to “supply current on” V_{DD_HV}” in $I_{DD_HV(FLASH)}$ row; updated $I_{DD_HV(PLL)}$ value—was $3 * f_{periph}$, is $30 * f_{periph}$; updated footnotes DSPI characteristics: added rows t_{PCSC} and t_{PASC} Added DSPI PCS strobe (PCSS) timing diagram